Aluminum Nitride Hydrolysis Enabled by Hydroxyl-Mediated Surface Proton Hopping

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ABSTRACT: Aluminum nitride (AlN) is used extensively in the semiconductor industry as a high-thermal-conductivity insulator, but its manufacture is encumbered by a tendency to degrade in the presence of water. The propensity for AlN to hydrolyze has led to its consideration as a redox material for solar thermochemical ammonia (NH₃) synthesis applications where AlN would be intentionally hydrolyzed to produce NH₃ and aluminum oxide (Al₂O₃), which could be subsequently reduced in nitrogen (N₂) to reform AlN and reinitiate the NH₃ synthesis cycle. No quantitative, atomistic mechanism by which AlN, and more generally, metal nitrides react with water to become oxidized and generate NH₃ yet exists. In this work, we used density-functional theory (DFT) to examine the reaction mechanisms of the initial stages of AlN hydrolysis, which include: water adsorption, hydroxyl-mediated proton diffusion to form NH₃, and NH₃ desorption. We found activation barriers (E_a) for hydrolysis of 330 and 359 kJ/mol for the cases of minimal adsorbed water and additional adsorbed water, respectively, corroborating the high observed temperatures for the onset of steam AlN hydrolysis. We predict AlN hydrolysis to be kinetically limited by the dissociation of strong Al–N bonds required to accumulate protons on surface N atoms to form NH₃. The hydrolysis mechanism we elucidate is enabled by the diffusion of protons across the AlN surface by a hydroxyl-mediated Grotthuss mechanism. A comparison between intrinsic (E_a = 331 kJ/mol) and mediated proton diffusion (E_a = 89 kJ/mol) shows that hydroxyl-mediated proton diffusion is the predominant mechanism in AlN hydrolysis. The large activation barrier for NH₃ generation from AlN (E_a = 330 or 359 kJ/mol, depending on water coverage) suggests that in the design of materials for solar thermochemical ammonia synthesis, emphasis should be placed on metal nitrides with less covalent metal–nitrogen bonds and, thus, more-facile NH₃ liberation.

KEYWORDS: metal nitride, hydrolysis, corrosion, density functional theory, proton hopping, thermochemical redox, ammonia synthesis

1. INTRODUCTION

Aluminum nitride (AlN) is a large, direct-band-gap semiconductor material with a unique array of properties including high thermal conductivity (319 Wm⁻¹K⁻¹, theoretical at room temperature),¹ low electrical conductivity (resistivity >10¹³ Ω cm),² high mechanical strength (>400 MPa),³ and a thermal expansion coefficient (4.3 × 10⁻⁶ K⁻¹ at room temperature)⁴ near that of silicon. This remarkable combination of properties makes AlN highly valuable as a packaging material for integrated circuits and multichip modules. However, the propensity for AlN to hydrolyze and produce ammonia (NH₃) precludes the use of water during its processing, mandating the use of organic solvents, such as isopropanol, which increases the cost and complexity of manufacturing AlN substrates.⁵ Despite these challenges, dense, polycrystalline AlN has been implemented as a substrate in high-power microelectronics for over three decades.⁶ Currently, polycrystalline AlN is primarily produced commercially by two processes: carbothermal nitridation, which involves nitridation of carbon and alumina (Al₂O₃) powders,⁶ and direct nitridation,⁷ which involves the nitridation of atomized aluminum.

With the continued advances of nanotechnology and device scaling, the electronics industry is faced with the progressively more difficult challenge of thermal management of increasingly dense electronics and integrated circuits. This is even a major issue for power electronics with their low device densities. For instance, thermal management is especially critical in the case of light-emitting diodes (LEDs) where, in general, LED lumen efficiency drops by 0.3–0.5% for every 1 °C increase in operating temperature,⁸ and consequently, heat dissipation is an important factor in determining LED performance. Therefore, efforts to develop more efficient heat-dissipation technologies in LED substrates have led to a transition away
from Al₂O₃, with a fully dense thermal conductivity of 20–35 Wm⁻¹K⁻¹ at room temperature,⁹ to AlN, with a polycrystalline thermal conductivity exceeding 200 Wm⁻¹K⁻¹.¹⁰⁻¹² However, to achieve these high thermal conductivities, AlN must be processed under strict conditions to avoid oxidation via hydrolysis because oxygen impurities in AlN have been identified as the primary cause of reduced thermal conductivity of dense AlN.¹³⁻¹⁵ In fact, reducing the intragranular oxygen content by 50% has been shown to increase the thermal conductivity of dense parts by as much as 41%.¹⁶ This motivated a number of studies that investigated functionalization of the AlN surface to prevent hydrolysis.¹⁷⁻²⁰ Although some success has been achieved in delaying the onset of hydrolysis in aqueous environments, these approaches involve the use of surface treatments that themselves can decrease the thermal conductivity of AlN.

AlN has also drawn interest as a metal-nitride redox material for NH₃ production from steam as a renewable alternative to the energy- and fossil-fuel-intensive Haber-Bosch process with significantly lower environmental impact. Numerous research efforts have sought an atmospheric pressure alternative to the Haber-Bosch process, which operates at extremely high pressure (up to 30 MPa) and consumes approximately 2% of the world’s energy production in the form of fossil fuels to both produce the H₂ that eventually becomes incorporated into NH₃ and drive the technologically challenging conversion of H₂ and N₂ to NH₃.²¹⁻²³ In recent years, a strategy analogous to redox cycling for solar thermochemical water splitting has emerged for the production of NH₃ using solar energy to drive a thermochemical redox cycle where a metal oxide is reduced with hydrogen, carbon monoxide, or solid carbon in the presence of nitrogen to produce a metal nitride that is subsequently hydrolyzed by steam to reform the metal oxide and produce NH₃.²⁰⁻²⁵ For a cycle using Al as the metal-nitride redox material,²⁶ the reduction step is shown as reaction 1, and the desired hydrolysis of AlN step is shown as reaction 2:

\[
\text{Al}_2\text{O}_3 + \text{N}_2 + 3\text{C} \rightleftharpoons 2\text{AlN} + 3\text{CO} \quad (1)
\]

\[
2\text{AlN} + 3\text{H}_2\text{O} \rightleftharpoons 2\text{NH}_3 + \text{Al}_2\text{O}_3 \quad (2)
\]

The viability of this alternative route to NH₃ production is dependent upon a robust metal-nitride redox material with favorable thermodynamics and kinetics for the reduction and oxidation reactions, i.e., reactions 1 and 2. To understand how to design redox materials to accommodate both reactions favorably, a fundamental understanding of the detailed, active reaction mechanisms is paramount.

Only a few studies of the kinetics of metal-nitride hydrolysis have been reported,²⁶⁻³⁶ and a quantitative description of the hydrolysis mechanism and bonding in metal nitrides is lacking.²⁷ Previous experimental work has described hydrolysis subsequent to the initial oxidation of AlN to form an oxidized film using a shrinking core model, which has been utilized to describe the kinetics of hydrolysis and to elucidate the associated kinetic parameters for this reaction.²⁶,²⁹ However, there has been some disagreement in the literature as to the identity of the rate-determining step for AlN hydrolysis. It has been suggested that AlN hydrolysis is limited by either solid-state diffusion²⁹ or by the initial surface reactions required to liberate N from the AlN lattice.²⁶ The lack of a detailed and quantitative mechanistic description increases the challenge of engineering metal nitrides to either increase the rate of hydrolysis for thermochemical NH₃ generation or decrease this rate to render particles hydrolysis-resistant. In this work, we report a detailed mechanism of AlN hydrolysis predicted using density functional theory (DFT), which identifies the surface reactions that control the rate of AlN hydrolysis and their associated activation barriers. We found that hydroxyl-mediated surface proton diffusion enables the accumulation of protons to form NH₃. Although the diffusion of protons on surfaces by either intrinsic or mediated processes is a key step in a number of important processes, including catalytic hydrogenation and dehydrogenation,³⁰⁻³³ hydrogen storage,³⁴ and conductivity in fuel cells,³⁵ detailed investigations of surface proton diffusion have been primarily limited to titania and, more recently, iron oxide.³⁶ In this work, we use DFT to investigate the mechanism of AlN hydrolysis and the roles of intrinsic and hydroxyl-mediated surface proton diffusion in AlN hydrolysis.

2. RESULTS AND DISCUSSION

We conducted periodic plane wave DFT calculations using the PBE functional to describe reactions of H₂O with the (110 00) AlN surface, shown in Figure 1. We modeled the AlN (110 00) surface using a 96 atom slab to describe the reaction mechanism of the initial hydrolysis of AlN, which generates NH₃ and introduces oxygen into the AlN lattice. In the (110 00) AlN surface, subsurface (bulk) Al atoms form four bonds with N. Likewise, subsurface N atoms form four bonds with Al. These bonds are of approximately 75% covalent and 25% dative character because the lone pair of nitrogen forms a dative bond with the empty sp³ orbital of Al. Surface Al atoms are bonded to two surface N atoms and one subsurface N. Likewise, surface N atoms are bonded to two surface Al atoms and one subsurface Al. These bonds are nominally covalent but possess some ionic character due to the electronegativity difference between N and Al. Surface N atoms possess a lone pair, and surface Al atoms possess an empty orbital that create surface Lewis base and acid sites, respectively.

Figure 1. (a) Supercell model (2 × 2) of the (11 00) surface (top-down view). (b) Supercell with six layers (side view). (c) Supercell with six layers (side view). The smaller purple spheres represent nitrogen atoms, and the larger blue spheres represent aluminum atoms. Surface Al atoms are labeled 1 through 8 for reference.
We found that H₂O reacts with AlN to hydrolyze the surface through four primary steps: (1) water adsorption, (2) proton migration to form NH₂* and NH₃*, (3) N surface vacancy formation and immediate filling by O*, and (4) NH₄* desorption. Throughout the text, "*" denotes a surface species. Details of the calculations can be found in the Methods section.

2.1. Water Adsorption and Dissociation. The initial hydrolysis of the bare AlN surface (Figure 1) commences with molecular H₂O adsorption followed by dissociation. We determined the preferred H₂O adsorption geometry by relaxing six unique initial configurations of adsorbed H₂O. These initial configurations all relaxed to the molecularly adsorbed state H₂O* shown in Figure 2a with an exothermic adsorption energy of E_ads = −162 kJ/mol. In this state, H₂O* acts as a Lewis base where an oxygen lone pair donates into the empty sp³ orbital of the surface Al atom, which acts as a Lewis acid, to form an Al−O dative bond. However, the relaxation mixes the bond character of the Al atom’s Al−O bond and its three Al−N bonds to produce bonds of mixed dative−covalent character (Figure 2a). The two neighboring N surface atoms hydrogen bond through their lone pairs with each H atom of H₂O* to further stabilize the molecularly adsorbed state.

Once adsorbed on the surface, H₂O* readily dissociates (Figure 2b) with a reaction energy and activation barrier of −31 and 3 kJ/mol, respectively. This results in an adsorption energy for the H₂O dissociated state (NH₂* and Al−OH*) of −193 kJ/mol. The exothermicity of adsorption in both the molecularly and dissociatively adsorbed states is primarily attributed to the formation of Al−OH* and N−H* bonds of mixed dative−covalent character, with further stabilization provided by the two H-bonds formed in both states.

At least two water molecules must dissociate to provide the three hydrogen atoms required for NH₃* formation. Therefore, we considered the adsorption of a second H₂O molecule at each of the remaining bare Al sites of the surface supercell in the configuration depicted in Figure 2b. The most favorable dissociative adsorption configuration for the second adsorbing H₂O is shown in Figure 3a. This configuration for two dissociatively adsorbed H₂O molecules is preferred due to the high degree of hydrogen bonding with the first dissociatively adsorbed H₂O, which leads to the more favorable adsorption of the second water (E_ads = −269 kJ/mol) relative to the first dissociative H₂O adsorption event.

2.2. NH₄* Formation. NH₄* could nominally form directly by proton transfer (PT) to NH* from a dissociatively adsorbing H₂O or by proton migration between two NH* sites formed by two dissociatively adsorbed H₂Os. Transition state (TS)

Figure 3. (a) Dissociation of a second H₂O forms two OH* and two NH*. This configuration mimics the configuration described for dissociative adsorption of a single H₂O. (b) NH₂* intermediate formed by proton transfer between two neighboring NH* sites by a hydroxyl-mediated proton relay.

searches for the direct path fail to identify a low-energy TS for direct PT and instead optimize to a minimum associated with the dissociatively adsorbed state of the second H₂O. From this low-energy initial configuration of two dissociated H₂O molecules (Figure 3a), NH₂* (Figure 3b) forms through a two-step proton relay mechanism mediated by OH*, as depicted in Figure 4. In the first step, the proton of one NH* transfers to a neighboring OH* to transiently reform molecular water, H₂O*, at the transition state (TS1); the transient molecular water then transfers its original proton to an adjacent bare N site to form an intermediate NH* surface species. The first PT from NH* to OH* occurs along the entrance channel of the first step of the reaction, and the second PT from the transiently formed H₂O* to N to form the NH* intermediate occurs along its exit channel. The net result of this endothermic proton relay is to transfer an adsorbed proton from a surface NH* far from the active NH* site, where NH₃* will form, to a N closer to the active NH* site. From this configuration, a second PT occurs to form NH₂*. First, the NH* proton transfers to OH* to again transiently form H₂O*, and then a proton transfers from H₂O* to form NH*. Like the first PT step, the second PT step is mediated by OH*. The TS of this second proton relay (TS2) involves a ∼120° rotation of OH* to orient the transient H₂O* for the final PT to NH* to form NH₂*, although H₂O* can also rotate to orient its other proton for PT to NH*. In both PT steps, the TS appears to be a molecularly adsorbed state that could be a plausibly stable adsorption configuration. However, in relaxing states akin to TS1 and TS2, no stable molecular H₂O* states were found, instead optimizing to one of the 2NH* dissociated states shown in Figure 4. It is also plausible that the 2NH* state (Figure 3a) could form NH₂* (Figure 3b) directly through a larger rotation of the molecularly adsorbed state (TS1), thus bypassing the intermediate 2NH state. However, in this potential single-step pathway, transition state TS2 is unavoidable, and thus this pathway would proceed with the same activation barrier as the two-step pathway shown in Figure 4. The two-step pathway through the 2NH* intermediate is thus shown for completeness, as the 2NH* intermediate is energetically stable relative to TS2 and NH₂*.

The proton relays of the first and second steps are analogous to proton transfers in aqueous and other hydrogen-bonded liquids that operate by the Grothuss mechanism. However, in this case, the process occurs on a partially hydroxylated surface where a hydroxyl acts as the mediator that accepts and donates the transferring protons via transient H₂O* formation rather than within the hydrogen-bonded network of a liquid, where H₂O mediates PT via transient H₂O* formation.
near the surface may also contribute to enhanced proton diffusion through a more traditional bulk Grothuss-like transport mechanism, where H$_2$O mediates PT through the formation of H$_2$O$^\circ$ intermediates.

We calculated the hydroxyl-mediated PT to form NH$_2^*$ to be endothermic by 135 kJ/mol and to proceed over a barrier of 198 kJ/mol, as shown in Figure 4. The endothermicity of this reaction is explained by the requirement that to accommodate a second proton at the NH$^*$ site to form NH$_2^*$, one of the three mostly covalent Al–NH$^*$ surface bonds must dissociate.

Aqueous-phase proton-relay mechanisms mediated by water via a Grothuss-like mechanism have been reported to provide low-energy pathways for a number of reactions. Although surface Grothuss-like mechanisms where the OH$^*$ surface species mediate the PT and H$_2$O$^*$ transiently forms are less common, proton conduction mechanisms mediated by adsorbed hydroxyl groups have also been previously reported. However, to the best of our knowledge, this is the first reported ab initio description of a Grothuss-like proton transport mechanism across a solid surface mediated by immobile surface hydroxyl groups in the absence of solvation.

To further examine how the hydroxyl-mediated proton relay catalyzes the formation of NH$_2^*$, we investigated NH$_2^*$ formation in the absence of OH$^*$. The NH$_2^*$ formation barrier in this case is 412 kJ/mol (Figure 4), substantially larger than the 198 kJ/mol barrier to NH$_2^*$ formation mediated by the hydroxyl-mediated proton relay, also shown in Figure 4. This indicates that the adsorbed hydroxyl groups catalyze NH$_2^*$ formation by reducing the activation barrier to proton transport by more than 200 kJ/mol and thereby facilitate surface proton transfer. Our calculations of proton transport in the absence of OH$^*$ also provide insight into the mechanism of AlN hydrolysis. The first step of the proton transport from the more stable NH$_2^*$ site to the intermediate NH$^*$ site is endothermic in the presence of OH$^*$ (first step of Figure 4) but approximately thermoneutral in the absence of OH$^*$ (first step of Figure 4). This is because in the absence of OH$^*$, all NH$^*$ sites are approximately equivalent energetically due to the absence of a hydrogen-bonding network that requires specific arrangements of the NH$^*$ and OH$^*$ surface groups to maximize stability. Consequently, the endothermicity for this first step in the presence of OH$^*$ arises from the loss of hydrogen bonding due to the transfer of a proton from the most-favorable N site to a less-favorable site, although the proton relay results in a different proton occupying the intermediate NH$^*$ site than the proton that occupied the initial, lower energy NH$^*$ site.

In the second step of the reaction to form NH$_2^*$, we calculate that the transport of the proton to form NH$_2^*$ is endothermic both in the presence and absence of OH$^*$ (second steps of Figure 4). Therefore, this endothermicity cannot stem solely from the loss of hydrogen bonding because no hydrogen bonding exists in the absence of OH$^*$. The formation of the NH$_2^*$ intermediate requires that a surface N, which was initially bonded to three neighboring Al atoms, breaks an Al–N bond to accommodate the second proton because a 5-fold coordinated N would involve a prohibitively high-energy rehybridization. Thus, the endothermic nature of the second proton relay step results from the dissociation of the mostly covalent Al–N surface bond to form NH$_2^*$. Figure 4 illustrates that the overall presence of OH$^*$ reduces the activation barrier required to transport protons across the AlN surface by more than 200 kJ/mol. Our results are unique in demonstrating the mechanism by which OH$^*$ formed by H$_2$O dissociative adsorption mediates the transport of protons across a metal
concerted step is exothermic by 120 kJ/mol, with an activation 
covalent 
formation of the N 
the partially concerted step is net exothermic as a result of the 
species, now bonded to a single Al through an Al 
away from the surface as it becomes a molecularly adsorbed 
adatom. That is, the Al 
oxide, resulting in mobile OH and H 
through adsorption into oxygen vacancies within the native 
oxide, resulting in mobile OH and H 
states.

We also considered the propensity to form an NH$_3$* intermediate from the single dissociated water structure depicted in Figure 2b. However, we found that the formation of a stable NH$_3$* intermediate from a single water is too unfavorable for a surface N to form two NH$_2$* bonds (thus breaking one Al–N bond) in the presence of a neighboring O* adatom. That is, the Al–OH* + (3Al)–NH$_2$* state is significantly more favorable than the Al–O* + (2Al)–NH$_2$* state.

2.3. NH$_3$ Formation by Proton Migration Involving Two Adsorbed Waters: “Two-Water Case”. Subsequent to the NH$_3$* formation (Figure 4) described previously, a third proton must transfer from a neighboring OH* to the NH$_3$* to produce NH$_2$*. The two-water case described here involves only two dissociated H$_2$O*$_3$'s, but alternative pathways involving additional dissociatively adsorbed H$_2$O molecules are also possible and will be discussed below. For NH$_2$* to accommodate the third proton and form NH$_3$*, it must break another Al–N bond, analogous to the dissociation of an Al–N bond to accommodate the second proton in the formation of NH$_2$* that avoids high-energy 5-fold coordinated N. Dissociation of the second Al–N bond causes NH$_3$* to relax away from the surface as it becomes a molecularly adsorbed species, now bonded to a single Al through an Al–N bond of primarily dative character (Figure 5a). This step to form NH$_3$* generates a transient N vacancy in the surface. The two-water mechanism to form NH$_4$* involves PT from the neighboring OH* to NH$_3$* to form NH$_2$*, and the resulting O adatom concomitantly relaxes into the transiently formed surface N vacancy, as shown in Figure 5a. As the O–H bond of OH* dissociates, the O atom forms two Al–O bonds of mixed covalent–dative character. We calculate that this partially concerted step is exothermic by 120 kJ/mol, with an activation barrier of 195 kJ/mol.

Although the dissociation of an Al–N bond to form NH$_3$* involves an energy penalty equal to the Al–N bond strength, the partially concerted step is net exothermic as a result of the formation of the N–H bond and the two additional Al–O bonds that form as O fills the N vacancy. Despite the moderately exothermic nature of this step, it involves a relatively large 195 kJ/mol barrier. This is because this step involves the dissociation (O–H and Al–N bonds) and formation (N–H, two Al–O bonds) of several bonds where the high-energy Al–N bond dissociations occur before the O can fill the vacancy. This step occurs sequentially because the N must first vacate its position to form the vacancy, which can then be filled by the O adatom. Because the two Al–O bonds form subsequent to the dissociation of the O–H and Al–N bonds, a late transition state arises where the two bond dissociations are relatively decoupled from the formation of the two Al–O bonds that cause this step to be exothermic. This step establishes a mechanism that concomitantly forms NH$_3$* and introduces oxygen into the AlN lattice during the initial hydrolysis of AlN. The overall pathway from the state with two adsorbed waters (2NH$_2$*, Figure 3a) to the molecularly adsorbed NH$_3$* state (Figure 5a) has an activation barrier of 330 kJ/mol (Figure 5b). The magnitude of this barrier agrees with the experimental observation that hydrolysis of AlN is slow under conditions where AlN is exposed to steam below 950 °C.26,29 We attribute this relatively large activation barrier to the successive dissociation of strong Al–N bonds at the surface to liberate N from the AlN lattice. We note that reporting a single activation barrier for three successive elementary steps will not capture the kinetic details of this reaction. Alternatively, a kinetic Monte Carlo model based on our predicted energetics could more completely describe the overall reaction kinetics, but this is beyond the scope of this work. The energies of each stable and transition state shown in Figure 5b can be found in Table S2.

The desorption of NH$_3$* involves the dissociation of the Al–N bond between the molecularly adsorbed NH$_3$* and the Al surface site to which it is bound and is calculated to be endothermic by 184 kJ/mol. This relatively large endothermicity is due to dissociation of the third and final Al–N bond, which is stronger than might be expected on the basis of a surface dative bond and the energy required to form NH$_2$ because although the Al–N bond is nominally a dative bond, it is partially covalent in character. This increased covalency arises from the fact that the surface Al to which the NH$_3$ is bound is also bound to a 3-fold coordinated O. This O atom provides additional electron density to the Al atom, increasing the dative character of the Al–O bond and thus increasing the covalent character of the Al–N bond to NH$_3$*, which consequently decreases the covalent character of two of the N–H bonds.

Figure 5. (a) Structure of the NH$_3$* surface site that forms from the reaction between OH* and NH$_3$*. The formation of NH$_3$* forms a N vacancy in the AlN surface that is filled by the O atom from dissociating OH*, which provides the proton. (b) Schematic potential energy surface for NH$_3$ formation and desorption through the “two-water” mechanism. Each labeled structure is illustrated in the following figures: NH* (Figure 2b), 2NH* (Figure 3a); NH* (Figure 3b); and NH* (Figure 5a). A table of the energies of each stable and transition state shown in Figure 5b is provided in Table S2.
This is exhibited by the lengthening of two of the N–H bonds of NH₃*, where two are 1.04 Å long and the third is 1.02 Å long. The N–H bond of desorbed NH₃ is calculated to be 1.02 Å, illustrating that two of the N–H bonds of NH₃* have decreased covalent character, enabling the strengthened Al–N bond.

2.4. NH₃ Formation with an Additional Adsorbed H₂O: “Three-Water Case”. Having elucidated the initial AlN hydrolysis mechanism of AlN oxidation and NH₃ liberation for the case involving the minimum number of dissociated H₂O molecules, we next investigated potential hydrolysis pathways involving additional dissociatively adsorbed H₂O that would be present at higher coverages of H₂O. For the simplest case of hydrolysis with additional water present, we modeled the adsorption and dissociation of a third H₂O (Figure 6a) to the surface with the minimum-energy 2NH* configuration resulting from two dissociatively adsorbed H₂O molecules (Figure 3a). The third H₂O molecule was predicted to adsorb to the surface with an adsorption energy of −202 kJ/mol, falling between the adsorption energies of the first and second dissociatively adsorbed H₂O molecules. The added energetic benefit of hydrogen bonding of this adsorbed H₂O to neighboring NH* and OH* groups on the surface leads to a slightly more-favorable adsorption than the first water. However, steric effects and lattice strain as a result of the increased coverage of OH* and NH* on the surface diminish the energetic benefit of the additional hydrogen bonding, as compared to the adsorption of the second water.

The formation of NH₃* (Figure 6b) is analogous to the mechanism we predicted for the two-water case (Figure 4); we calculated that NH₃* is again formed by an endothermic hydroxyl-mediated proton relay. However, for this case, we calculated that the formation of NH₃* is more endothermic and kinetically unfavorable than for the corresponding two-water reaction, with an endothermicity and activation barrier of 196 and 317 kJ/mol, respectively. The larger endothermicity and barrier are attributed to the additional hydrogen bonds of the denser hydrogen bond network that must be disrupted in the three-water case relative to the two-water case. Additionally, steric effects caused by the higher coverage of adsorbed H₂O hinder the dissociation of the Al–N bond that accompanies NH₃* formation.

From the NH₃* state, we again predict that NH₃* (Figure 6c) is formed from a hydroxyl-mediated proton relay, as in the two-water case. However, because the hydrogen-bonding network has already been locally disrupted in the process of forming NH₃*, this step was calculated to be substantially less-unfavorable than NH₃* formation, with an endothermicity and activation barrier of 83 and 162 kJ/mol, respectively. In contrast to the two-water case where NH₃* formation is coupled with surface oxidation, NH₃* forms via a two-step mechanism in the three-water case; NH₃* is first formed by a proton relay from NH*. In this case, each of the three dissociatively adsorbed H₂Os provide one proton to form NH₃*, three OH* intermediates, and a surface N vacancy. This structure is stabilized by significant hydrogen bonding, and its N vacancy is filled by an O atom provided by a neighboring OH* through a concerted PT from the OH* to a neighboring OH* to form H₂O*. (Figure 6d). This provides a low-energy pathway to form NH₃* and the associated intermediate N vacancy and to subsequently fill the N vacancy. Examination of the structure of the N vacancy (Figure 6c) shows that in the case of additional water, the additional OH* groups on the surface hydrogen bond with the newly formed NH₃* to effectively hinder it from relaxing fully to its top position above a surface Al atom. The relaxation of NH₃* to the top position enables the exothermic oxidation of the AlN surface by a neighboring OH* group, which readily transfers its proton to another neighboring OH* in the process of filling the vacancy (Figure 6d). Finally, NH₃* desorbs with a desorption energy of 189 kJ/mol, nearly identical to that predicted for the two-water case, which should be expected given that the adsorbed NH₃* that results after the oxidation step does not form H bonds with

Figure 6. (a) 3NH* resulting from the dissociative adsorption of three H₂O molecules. (b) NH₂* formed from a hydroxyl-mediated proton relay. (c) NH₃* and a transiently formed N surface vacancy. (d) NH₄* following filling of the N vacancy by O that leads to surface oxidation. (e) NH₃ formation and desorption pathway for the three-water mechanism. NH* (Figure 2b); 2NH* (Figure 3a); 3NH* (Figure 6a); NH₂* (Figure 6b); and NH₃* (Figure 6d). A table of the energies of each stable and transition state shown in Figure 6e is provided in the Table S3.
any neighboring adsorbates and thus appears analogous to the adsorbed NH₄⁺ of the two-water case.

The schematic potential energy surface for the complete pathway from 3NH⁺ and 3OH⁻ to desorbed NH₄ and an oxidized surface site is shown in Figure 6 and was calculated to have an activation barrier of 359 kJ/mol. This barrier is comparable to that seen in the two-water case (330 kJ/mol), although it is slightly larger as a result of the required dissociation of additional hydrogen bonds in the denser hydrogen bonding network associated with the 3NH⁺ + 3OH⁻ state compared with the 2NH⁺ + 2OH⁻ state of the two-water case. Comparing the two-water and three-water pathways, we find that the mechanisms are similar. In both cases, it is the dissociation of the two Al–N bonds that are required for the accumulation of three protons at a surface N that gives rise to the large barriers associated with hydrolyzing AlN. These large barriers to liberating nitrogen from the AlN lattice explain the slow initial conversion of AlN into NH₃ and Al₂O₃ by hydrolysis at moderate temperatures (<950 °C). As mentioned in the discussion of the two-water pathway, a more rigorous analysis of the reaction kinetics could involve the construction of a kinetic Monte Carlo model, which was deemed outside the scope of this work.

Our analysis does not consider the continued hydrolysis of AlN, which likely involves the formation of an oxynitride (Al−O−N) and ultimately an Al₂O₃ film on the surface and the diffusive transport of O²⁻ and N³⁻ ions through the oxide film of the oxidizing particle. We instead focused on the initial steps, which introduce oxygen into the AlN lattice that begin the liberation of N in the form of NH₃. The results of our theoretical work indicate that a large barrier (~350 kJ/mol) is associated with the initial surface reactions that must occur at the onset of AlN hydrolysis and NH₃ generation. The barriers calculated for NH₃ formation from AlN of approximately 350 kJ/mol are considerably larger than would be expected for a solid-state diffusion process, suggesting that the rate-determining step of the initial hydrolysis of AlN is the initial reaction at the surface and not the diffusion through the oxidizing particle. This may also be true for subsequent oxidation of the partially oxidized AlN particle, which possesses a core–shell structure with an Al−O−N film, where oxidation presumably involves analogous reactions to form NH₃ from N atoms at the surface. However, we note that a first-principles elucidation of the detailed mechanism and energetics becomes complicated after the initial hydrolysis of the bare AlN surface, where a large number of possible structures of the partially oxidized surface are possible and solid-state diffusion begins to play a larger role. Additionally, the dissociation of NH₃ into N₂ and H₂ may become relevant at elevated temperatures and at the later stages of hydrolysis. This work is a first step in understanding this complex process but does not purport to describe the later stages of AlN hydrolysis, where the surface is less well-defined and where solid-state diffusion and NH₃ decomposition may play a larger role.

3. CONCLUSIONS

We have performed ab initio quantum chemical calculations on plausible pathways for the hydrolysis of the (11 00) surface of wurtzite AlN. First, we considered six unique H₂O adsorption geometries to identify the lowest energy configuration of dissociatively adsorbed H₂O, H₂O that dissociatively adsorbs to the AlN surface to form N−H⁺ + Al−OH⁺ is the most stable of those evaluated. Subsequently, reaction paths involving a second adsorbed H₂O were considered for the formation of the NH₄⁺ intermediate. The NH₄⁺ intermediate forms via a surface hydroxyl-mediated proton-relay mechanism, which is a surface Grothuss-like proton relay where adsorbed hydroxyls act to mediate the proton relay. The formation of NH₄⁺ is accompanied by the dissociation of one of the three Al–N bonds at the NH⁺ center. In this analysis, we also identify the dissociation of predominantly covalent Al–N bonds as the primary cause of the large barriers that results in the kinetic challenge of liberating nitrogen from AlN by hydrolysis in the case of thermochemical NH₃ generation. From the NH₄⁺ intermediate, we find a similar Grothuss-like mechanism for NH₄⁺ formation. During the proton migration through the proton relay and the Al–N bond dissociation step, we predict that a N vacancy is formed, which is subsequently filled by a surface O. In the case of low H₂O coverage, this step is partially concerted where the N vacancy forms transiently as it is concomitantly filled by an O surface atom and NH₃ forms. We elucidate a similar mechanism for the case of additional water present on the AlN surface. In the case of higher H₂O coverage, the NH₃ generation step involves the formation of an intermediate N vacancy and NH₄⁺, where the N vacancy is subsequently filled by a surface O atom.

We calculate activation barriers for the overall hydrolysis reaction to be 330 or 359 kJ/mol for minimal water coverage and additional water coverage cases, respectively. These results are corroborated by previous experimental work that demonstrated that little or no conversion of AlN to NH₃ occurs below 950 °C. In the elucidation of this mechanism and the associated energetics, we present an enhanced understanding of the behavior of AlN and, more broadly, metal nitrides when exposed to water, thereby oxidizing and liberating nitrogen as NH₃. These results have important implications for designing processes that either avoid oxidation by hydrolysis (for example, in the case of processing AlN powder for thermal-management applications) or for designing materials that possess favorable thermodynamics and kinetics for solar thermal redox processes using metal nitrides to efficiently generate carbon-free NH₃. In the search for metal nitrides with fast-oxidation kinetics for carbon-free NH₃ synthesis, it is important to consider the metal–nitrogen bond strength, which can be correlated to the metal–oxygen bond strength of the accompanying oxide. The mechanism we predict for AlN hydrolysis involves nitrogen liberation in the form of NH₃ and large activation barriers associated with the dissociation of mostly covalent Al–N bonds, which explains the slow experimentally observed hydrolysis kinetics. However, a metal nitride with metal–nitrogen bonds with less covalent character will result in lower activation barriers to NH₃ generation and thus improved hydrolysis kinetics.

4. METHODS

Plane-wave periodic-boundary-condition DFT calculations were performed using the Vienna Ab Initio Simulation Package. All calculations employed the Perdew–Burke–Ernzerhof (PBE) generalized gradient approximation (GGA) exchange and correlation functional coupled with projector augmented wave (PAW) pseudopotentials. For these calculations, PAWs were used to explicitly describe the aluminum 3s and 3p; nitrogen 2s and 2p; oxygen 2s and 2p; and hydrogen 1s electrons. A 96 atom, 2 × 2 supercell of the (11 00) surface of wurtzite AlN was used as the model for the reacting surface. This crystal structure was chosen because Schmerler et al. showed that the wurtzite phase is the stable structure at the conditions of interest for electrical and NH₃ generation.
et al. showed that by far the lowest surface energy facet is the (11\text{0}) surface. The 96 atom slab consists of six AlN layers and has a thickness of 9.4 Å in a 24 × 4 Å thick supercell, meaning that 15 Å of vacuum space separates the reacting surface from the bottom layer of the adjacent slab (see Figure 1). To obtain the model surface, we allowed the bulk AlN wurtzite structure to fully relax, added vacuum space, and then allowed the top four layers of the slab to relax while the bottom two layers were frozen to mimic the bulk surface. All calculations utilized a 450 eV cutoff energy based on a cutoff energy convergence study over the range of 250–500 eV, where a 450 eV cutoff energy was found to produce a total energy within 0.01 eV/ supercell of that produced with a 500 eV cut-off energy. The slab was relaxed using various Monkhorst–Pack k-point meshes in 1 × 1 × 1 and 6 × 6 × 1, where the 3 × 3 × 1 k-point grid produced energies within 0.01 eV per supercell of those computed using the finer and more computationally demanding meshes. Bader charge analyses were conducted using software from the Henkelman group. All reaction-energy barriers were obtained using the climbing-image nudged-elastic-band (cNEB) method or a combination of cNEB and the Dimer method. All geometries, including cNEB images, were relaxed until the magnitude of the maximum force on the optimized ions was less than 0.03 eV/Å. Adsorption energies were calculated using eq 3:

\[ E_{\text{ads}} = E_{\text{surf/mol}} - E_{\text{surf}} - E_{\text{mol}} \]  

(3)

where \( E_{\text{ads}} \) is the energy of adsorption, \( E_{\text{surf}} \) is the energy of the perfect surface, \( E_{\text{surf/mol}} \) is the energy of the isolated adsorbing molecule in vacuum, and \( E_{\text{mol}} \) is the energy of the surface with the adsorbate.

## ASSOCIATED CONTENT

### Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acsami.6b04375.

Tables showing the energies of all stable and transitions states shown in Figures 4, 5b, and 6e. (PDF)

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**Notes**

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### REFERENCES


(34) Heyns, A. M.; Prinsloo, L. C.; Range, K.-J.; Stassen, M. Vibrational Spectra and Decomposition of α-Calcium Nitride (α-Ca3N2) and Magnesium Nitride (Mg3N2). J. Solid State Chem. 1998, 137 (1), 33–41.


